### **PNx High Peak Power Powerchip Series**

#### **Key features**

- Peak power up to 200kW
- Pulse width down to 350ps
- 1064nm, 532nm, 355nm and 266nm
- Single shot to 1000Hz
- **▶** Excellent beam quality, TEM00 M²<1.1
- All-in-one package



The PowerChip™ passively Q-switched MicroChip lasers offer the highest peak powers and shortest pulses at kilohertz repetition rates with an excellent beam quality.

They feature a completely integrated platform which includes the laser head, power supply and air cooling in a compact, rugged, and turnkey package.

### **Applications**

- Materials processing
  - o Inscribing glass
  - Via drilling printed circuit boards
  - Micromachining
- MALDI-TOF
- Microdissection
- Laser Induced Fluorescence (LIF)
- Time Resolved Fluorescence
- Laser Induced Breakdown Spectroscopy (LIBS)
- Light Detection and Ranging (LIDAR)

# For your application, find your pulsed laser solution

## teem photonics™

### **Technical specifications:**

	PNP-M08010 -1x0	PNG-M02010 -1x0	PNG-M04005 -1x0	PNV-M02510 -1x0	PNU-M01210 -1x0 <sup>(6)</sup>
Wavelength	1064nm	532nm	532nm	355nm	266nm
Max Repetition 1000Hz 100 Rate RR <sub>max</sub> (1)		1000Hz	500Hz	1000Hz	1000Hz
Constant Pulse width range (FWHM)	<500ps	<400ps	<400ps	< 350ps	<350ps
Output energy	>80µJ	>20µJ	>35µJ	> 25µJ	>12µJ
Peak Power	>160kW	>50kW	>80kW	> 60kW	>35kW
Short term (1min) pulse to pulse stability 1σ	≤ 1 %	≤ 3 %	≤ 3 %	≤ 3 %	≤ 3 %
Long term (1h) output power stability <sup>(2)</sup>	± 3%	± 3%	± 3%	± 5%	± 5%
Beam profile	Gaussian TEM00	Gaussian TEM00	Gaussian TEM00	Gaussian TEM00	See note (5)
Beam divergence (Full@1/e²) Horizontal Vertical	2.0±0.5mrad 2.0±0.5mrad	1.8±0.5mrad 1.8±0.5mrad	5.0±1mrad 4.0±1mrad	3.3±0.5mrad 3.0±0.5mrad	<0.9mrad <0.9mrad
M <sup>2 (3)</sup>	<1.3	<1.3	<1.3	<1.3	<1.4
Beam ellipticity <sup>(4)</sup>	<1.3	<1.3	<1.3	<1.3	-
Polarization	> 20 dB	> 20 dB	> 20 dB	> 20 dB	> 20 dB

	Notes
(1)	See options p3
(2)	For temperature variation <±3°C and <3°C/hour
_ (3)	Mean average value $M = \sqrt{(XY)}$ , X and Y being respectively the major and minor axis of the ellipse
(4)	Beam ellipticity is calculated as the ratio of the main axis far-field divergence.
_ (5)	Beam exhibits different profile in horizontal (Gaussian) and vertical (( $\sin x/x$ ) <sup>2</sup> in far-field) plans
(6)	Contact factory for availability
<b>(7)</b>	More compact separated leaser head and electronics package may be available upon request – Contact factory for further details

### **Complementary information & options:**

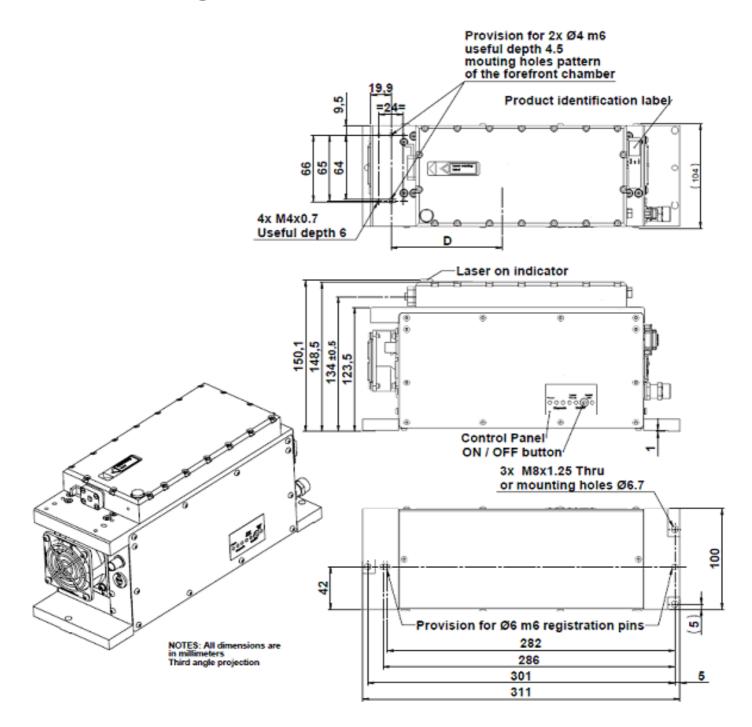
Environment parameters		
Operating Temperature	20-35 °C	
Maximum Power Consumption	<75 W	
Storage Temperature	0-50 °C	
Shock of 11ms according to IEC 68-2- 27, non operating	25 g	
Vibration 5Hz to 500Hz sinusoidal according to IEC 68-2-6, non operating	2 g	

Certification		
Laser Classification according to IEC 60825-1:2007	Class 3B Except PNU : Class 4	
CDRH	Yes if used with PCR-240500-100 power supply	
ROHs	Yes	

Package		
Laser Head dimensions, LxWxH <sup>(7)</sup>	311x100x149 mm	
Laser Head weight	5.5 kgs	
PCR-240500-100 AC/DC converter dimensions, LxWxH	315x262x77 mm	
PCR-240500-100 AC/DC converter weight	3 kgs	

Options		
Fixed Repetition Rate = RR $_{max}$	-100 version	
Fixed Repetition Rate ≠ RR <sub>max</sub>	-110 version ; RR to be chosen over 10Hz-RR $_{\rm max}$	
External Variable Repetition Rate	-120 version ; single shot to $RR_{\text{max}}$ , 1 optimized RR value	
External Variable Multi-Repetition Rate	-130 version ; single shot to $RR_{max}$ , 3 optimized RR values	

#### **Mechanical Drawings: CDRH Laser Head**



### <u>Mechanical Drawings : PCR-240500-100 (CDRH compliant AC/DC converter)</u>

